Study of optical conductivity of highly disordered MoC films by spectroscopic ellipsometry

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# Optical conductivity

Drude model

$$\sigma(\omega) = \sigma'(\omega) + i\sigma''(\omega) = \frac{\sigma_0}{1 - i\omega/\Gamma}$$

•  $\sigma_0 = n e^2 / m \Gamma$  is the DC conductivity, and  $\Gamma = 1 / \tau$ 

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### Quantum correction to conductivity

Weakly disordered metals

 $\sigma(\omega) = \sigma_{\rm reg}(\omega) + \delta\sigma(\omega)$ 

• Normal conductivity:

 $\sigma_{\rm reg}(\omega)\approx\sigma_0$ 

• Quantum correction  $\delta\sigma(\omega)$ :

- Weak-localization
- Interaction effects
- The same functional form
  - 3D:  $\delta\sigma(\omega) \sim \sqrt{\omega}$
  - 2D:  $\delta\sigma(\omega) \sim \ln(\omega)$



Temperature dependence

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- Theoretically should be present up to  $\omega^* \sim \Gamma$

### Transport measurements of MoC at low temperatures

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- $\blacksquare$  2D weak-localization and e-e interaction effects up to RT



J. Lee et al., PRB 49, 13882 (1994)

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"... extending the weak localization idea up to room temperature to interpret our data may be controversial."

- Magnetron sputtered in argon-acetylene atmosphere
- Mo target and sapphire substrates
- Sample characterisation sheet resistance  $\mathbf{R}_{\Box}=\rho/t$
- $Mo_x C_{1-x}$ ; stoichiometry tuned disorder acetylene flow rate
- Two sets of 5 nm thin samples:
  - 1. set:  $R_{\Box}$  from 420 to 720  $\Omega/\Box$
  - 2. set:  $R_{\Box}$  from 390 to 3900  $\Omega/\Box$

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How far do they extend?

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- Our experimental frequency range 80-1000 THz
- Spectroscopic ellipsometry
- Reflection measurement, evaluation of  $\sigma_1$  and  $\sigma_2$
- Our experimental frequency range 300-810 THz

### Optical transmission spectra

- 1. set of MoC:  $R_{\Box} = 420, 500, 590 a 720 \Omega/\Box$
- Smooth transmission spectra



- $T(\omega)$  decreases with frequency  $\omega/2\pi$
- The opposite is expected from Drude model

















• Agreement between 3 data sets,  $\hbar\Omega \approx 14 \text{ meV}$  up to 4 eV

• Postulate for the  $\sigma$ :

$$\begin{array}{lll} \sigma'(\omega,T) &=& \sigma_0 \left[ 1 - \mathcal{Q}^2 + \mathcal{Q}^2 \sqrt{\Omega/\Gamma} \right] & \mbox{if } \Omega < \omega^* \\ \sigma'(\omega,T) &=& \frac{\sigma_0}{1 + (\Omega/\Gamma)^2} & \mbox{if } \Omega \ge \omega^* \end{array}$$

- Imaginary part $\sigma''$  given by Kramers-Kronig relations
- 3 parameters:
  - 1. Q "Quantumness"
  - 2.  $\Gamma$  Scattering rate

3. 
$$\sigma_0 = ne^2/m\Gamma$$
, whereas  $\sigma(0,0) = \sigma_0(1-Q^2)$ 

• Fermi liquid theory, for interaction effects:

$$\Omega = \sqrt{\omega^2 + (\pi k_B T/\hbar)^2}$$

# Conductivity $\sigma(\omega)$ fit



 Observation of quantum corrections to conductivity up to optical frequencies, Phys. Rev. B 100, 241106(R) (2019)

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| $\mathbf{R}_s[\Omega/\Box]$ | $\mathbf{g}_0$ | $\mathbf{Q}^2$ | $\Gamma[\mathbf{eV}]$ | Λ    |
|-----------------------------|----------------|----------------|-----------------------|------|
| 390                         | 1.35           | 0.35           | 12.1                  | 1.85 |
| 500                         | 1.32           | 0.46           | 12.3                  | 1.54 |
| 560                         | 1.31           | 0.58           | 12.2                  | 1.74 |
| 660                         | 1.22           | 0.64           | 12.3                  | 1.92 |
| 1380                        | 1              | 0.83           | 13.4                  | 3.08 |
| 2240                        | 0.96           | 0.89           | 15.0                  | 3.39 |
| 3900                        | 0.83           | 0.95           | 15.2                  | 3.66 |

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- Metal Insulator transition is approached

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  - Randomly generated conductivity curves that obey the Kramers-Kronig relations and fit the experimental data to a chosen degree
  - Prolongation is given by the average of the selected curves
  - Reasonably smooth conductivity without rapid changes and oscillations fulfilled in strongly disordered (MoC) films

 Numerical extrapolation method for complex conductivity of disordered metals



■ S. Kern et al., Phys. Rev. B 103, 134205 (2021)

- Optical conductivity of MoC films;  $\mathbf{R}_s \in \langle 390, 3900 \rangle \Omega / \Box$
- Transport and optical measurements
- Observed quantum corrections to conductivity up to optical frequencies
- Parameters  $\sigma_0$ ,  $\mathcal{Q}$  and  $\Gamma$  were extracted
- Appropriate for the study of Metal-Insulator transition
- Utilized a numerical extrapolation method for complex conductivity of disordered metals

# Thank you for your attention

Neilinger et al., Physical Review B100, 241106 (R) (2019)
 S. Kern et al., Phys. Rev. B 103, 134205 (2021)